

**NEW ZEALAND INSTITUTES OF TECHNOLOGY AND POLYTECHNIC  
QUALIFICATIONS IN INFORMATION & COMMUNICATIONS TECHNOLOGY**

**PRESCRIPTION: BS500 SEMICONDUCTOR THEORY**

AIM OF MODULE:	Students will gain an understanding of the structure of semiconductor materials and the construction, characteristics and operational principles of semiconductor devices.
CREDITS:	14
STUDENT LEARNING HOURS:	140
CONTENT REVISED:	2008
PRESCRIPTION EXPIRY DATE:	Nov 2011

**Level and Assessment Schedule**

TOPICS	<u>Highest Skill Level</u>				<u>Suggested Assessment Percentage</u>
	R	C	A	P	
1. Semiconductor Materials		*			10
2. Diodes		*			15
3. Bipolar Transistors		*			25
4. Unipolar Transistors		*			25
5. Thyristor family of semiconductors		*			25
					<hr/> 100 <hr/>

## LEARNING OUTCOMES

The student will:

- |   |   |                                                                                                                                                                                                                |
|---|---|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C | 1 | Describe the atomic structure of semiconductor materials, differentiate between conductors, insulators and semiconductors and explain the principles associated with the production of semiconductor materials |
| C | 2 | Explain the construction, characteristics and principles of operation of diodes                                                                                                                                |
| C | 3 | Explain the construction, characteristics and principles of operation of bipolar transistors                                                                                                                   |
| C | 4 | Explain the construction, characteristics and principles of operation of unipolar transistors                                                                                                                  |
| C | 5 | Explain the construction, characteristics and principles of operation of thyristor family of semiconductors including SCRs, diacs, sidacs and triacs                                                           |

## Content

### 1 Semiconductor Materials

- Describing the atomic structure of semiconductor materials, differentiating between conductors, insulators and semiconductors and explaining the principles associated with the production of semiconductor materials includes:
- Resistivity of conductors, insulators and semi-conductors
  - Variations in conductivity due to changes in temperature
  - Silicon and germanium semi-conductor materials
  - Doping of semi-conductor materials
  - P and N type materials

### 2 Diodes

- Explaining the construction, characteristics and principles of operation of diodes includes:
- Circuit symbol and polarity
  - Conventional and electron current flow
  - Properties related to construction materials (silicon and germanium)
    - Forward voltage drop
    - Leakage current
    - Junction capacitance
    - Peak inverse voltage (PIV)
    - Characteristic curves

### 3 Bipolar Junction Transistors

- Explaining the construction, characteristics and principles of operation of bipolar junction transistors includes:
  - Schematic symbols of NPN and PNP
  - Forward biased base-emitter junction and reversed biased base-collector junction
  - Electron flow and characteristic family of curves for NPN and PNP
  - Effects of leakage current
  - Common base, common emitter, and common collector (emitter follower) configurations

### 4 Unipolar Transistors

- Explaining the construction, characteristics and principles of operation of unipolar transistors includes:
  - Schematic symbols of JFETs and MOSFETs
  - JFET and MOSFET construction
    - Cross section of a CMOS integrated circuit
    - Physical structure of the enhancement type of NMOS transistor
  - JFET and MOSFET enhancement and depletion modes
  - Characteristics of junction field-effect transistors

### 5 Thyristor Family of Semiconductors

- Explaining the construction, characteristics and principles of operation of thyristors, including silicon controlled rectifiers (SCRs), diacs, sidacs, and triacs, will involve:
  - Thyristor terms, symbols and definitions
  - Schematic symbols of SCRs, diacs, sidacs, and triacs
  - Block construction of SCRs
  - Basic operation and geometric construction (cross-sectional view) of;
    - An SCR
    - A diac
    - A sidac
    - A triac
  - Thyristor electrical characteristic curves
  - Thyristor switching methods

#### Note:

- The characteristics of the devices should be demonstrated by laboratory experiments.

## Reading/Reference List:

- Electronic Fundamentals: Circuits, Devices, and Applications (7<sup>th</sup> Edition). Thomas L. Floyd ISBN-13: 978-0132197090 (Published by Prentice Hall, April 9, 2006)
- Web links:
  - **Semiconductor Materials** [http://www.science-campus.com/engineering/electronics/semiconductor\\_theory/](http://www.science-campus.com/engineering/electronics/semiconductor_theory/) (Accessed August 2008)
  - **Diodes** [http://www.allaboutcircuits.com/vol\\_3/chpt\\_2/6.html](http://www.allaboutcircuits.com/vol_3/chpt_2/6.html) & [http://www.electronics-radio.com/articles/electronic\\_components/diode/pn-junction-diode.php](http://www.electronics-radio.com/articles/electronic_components/diode/pn-junction-diode.php) (Accessed August 2008)
  - **Bipolar Junction Transistors** [http://en.wikipedia.org/wiki/Bipolar\\_junction\\_transistor](http://en.wikipedia.org/wiki/Bipolar_junction_transistor) (Accessed August 2008)
  - **Unipolar Transistors** <http://www.ece.uvic.ca/~btill/uvatt/discrete/review.pdf> (Accessed August 2008)
  - **Thyristor Family of Semiconductors** <http://www.educypedia.be/electronics/composetriac.htm> & [http://www.littelfuse.com/data/en/Application\\_Notes/AN1001.pdf](http://www.littelfuse.com/data/en/Application_Notes/AN1001.pdf) (Accessed August 2008)